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Report:

The stiffness transition [1,2] is a simple and attractive idea for describing physical properties of network glasses using the averaged coordination number of systems. This idea was substantially developed experimentally by Boolchand and coworkers [3] as the so-called intermediate phase (IP) examined by thermodynamic and Raman scattering measurements. In As_xSe_{1-x} glasses [4], they expressed an opposition to the so-called 8 - N bonding rule proposed by Mott [5] experimentally based on the stiffness transition theory. It was found that non-reserving heat flow obtained from temperature-modulated differential calorimetry almost vanishes in the 0.29 < x < 0.37 composition range, separating the floppy glasses from the stressed rigid ones. Since the ideal boundary is x = 0.40 if the 8 - N bonding rule was strictly valid, they proposed a breakdown of this rule and suggested that 28.6% of $Se=As(Se_{1/2})_3$ quasi-tetrahedral units should exist in addition to the normal $As(Se_{1/2})_3$ pyramidal units around the As atoms.

We have carried out anomalous x-ray scattering (AXS) experiments on the As_xSe_{1-x} glasses at x = 0.40 [6], 0.33, and 0.29 [7], including the IP concentration, and the obtained differential structure factors $\Delta_k S(Q)$ were analyzed using reverse Monte Carlo (RMC) modeling for evaluating the partial structure factors $S_{ij}(Q)$ and the corresponding partial pair distribution functions $g_{ij}(r)$. In this report, we discuss the local- and intermediate-range partial structures in relation to the stiffness transition, the 8 - N bonding rule, and the existence of wrong As-As homopolar bonds.

The bulk $As_x Se_{1-x}$ glassy samples were obtained by quenching the melts in quartz

ampoules containing the mixed compound. The melts were homogenized at 600°C for at least 48 h before the samples were slowly quenched in air.

The AXS measurements were carried out at BM02 at two incident x-ray energies of 20 and 200 eV below the As (11.868 keV) and Se (12.658 keV) K edges. The measurements were performed in reflectance mode using a standard $\omega - 2\theta$ diffractometer installed at the beamline.

The RMC simulations were carried out using two $\Delta_k S(Q)$ s and the total structure factor S(Q). To avoid unphysical atomic configurations, three constraints were applied to the RMC modeling. Firstly the cut-off values were determined to be 0.235, 0.230, and 0.225 nm for the As-As, As-Se, and Se-Se atomic pairs. Secondly weak bond angle constraints were applied for each type to be about 100°. Finally a constraint of Se-Se bond fractions was applied around the Se atoms. These fractions were chosen from the results of an *ab initio* molecular dynamics (MD) simulation by Bauchy et al. [8].

Figure shows $g_{AsAs}(r)$ (left), $g_{AsSe}(r)$ (center), and $g_{SeSe}(r)$ (right) at x = 0.29 (top), 0.33 (middle), and 0.40 (bottom) obtained from the RMC modeling. The figure is taken from Ref. [7]. At x = 0.40, a small peak is observed at $r \sim 0.23$ nm in $g_{AsAs}(r)$ [6]. The existence of such homopolar wrong bonds were discussed in detail by Bauchy et al. [8] using *ab initio* MD simulation. With decreasing x, the As-As wrong bonds rapidly decreases in the IP concentration range, which is in good agreement with the *ab initio* MD data [8]. For the further discussion, the AXS experiment should be performed in the wider concentration range including the floppy glasses, which are now in progress.

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